

GIET UNIVERSITY, GUNUPUR – 765022

RD19BTECH012

	Registration No:	
Γotal	Number of Pages :2 AR-19 RECHAST GENERATED EXAMINATIONS (RECHAR) NOW/REG 2010	
	B.TECH 1 ST SEMESTER EXAMINATIONS (REGULAR), NOV/DEC 2019 BESBS1033 – Basics of Electronics	
		n : 70 Marks
	Answer ALL Questions	11
	The figures in the right hand margin indicate marks.	
	PART – A: (Multiple Choice Questions) $10 \times 1=10 \text{ Mark}$	
Q.1.	Answer <u>All</u> Questions.	
a	The forward voltage drop across a silicon diode is about	[CO 1][PO 1]
	a)2.5 V b)3 V c)10 V d) 0.7 V	
b	The most widely used rectifier is	[CO 1][PO 1]
	a) half-wave rectifier b) centre-tap full-wave rectifier	
	c) bridge full-wave rectifier d)none of the above	
c	The number of depletion layers in a transistor is	[CO 1][PO 2]
d	a)four b)three c)one d)two The power gain in a transistor connected in which arrangement is the highest	[CO 2][PO 2]
u	a)common emitter b)common base c)common collector d)none of the above	[CO 2][1 O 2]
e	If the reverse bias on the gate of a JFET is increased, then width of the conducting channel.	[CO 2][PO 1]
	a) is decreased b)is increased c)remains the same d)none of the above	
f	For an Op-amp with negative feedback, the output is	[CO 2][PO 1]
	a)equal to the input b)increased	[][-]
	c) fed back to the inverting input d)fed back to the noninverting input	
g	The input stage of an Op-amp is usually a	[CO 3][PO 1]
	a) differential amplifier b)class B push-pull amplifier	
h	c)CE amplifier d)swamped amplifier The material used to coat inside the face of CRT is	[CO 3][PO 1]
11	a) Carbon b)Sulphur c)Silicon d)Phosphorous	[CO 3][1 O 1]
i	Both OR and AND gates can have only two inputs.	[CO 4][PO 1]
	a) True b) False	
j	In 2's complement representation the number 11100101 represents the decimal number . a) $+37$ b)-31 c)+27 d)-27	[CO 4][PO 1]
	PART – B: (Short Answer Questions) 10x2=20 Marks	
Q.2.	Answer ALL questions	
a	Explain the term doping and its need?	[CO1] [PO1]
b	Why diodes are not operated in the breakdown region in rectifiers?	[CO1] [PO1]
c	Discuss the need for biasing the transistor?	[CO1] [PO1]
d	What is Op-Amp?	[CO2] [PO2]
e	What is the use of horizontal and vertical amplifier in CRO?	[CO2] [PO1]
f	How α and β are related to each other?	[CO2] [PO2]
g	Represent -27 in 2's complement form.	[CO3] [PO1]
h	Why a two-input NAND gate is called universal gate?	[CO3] [PO1]
i	What is meant by LED? What precautions are required to be observed in the use of LEDs?	[CO4] [PO1]
j	What are the main purposes for which a common-collector amplifier may be used?	[CO4] [PO1]
	PART – C: (Long Answer Questions) 4x10=40 Marks	



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Answer ALL questions

Q.3	3				
a	Explain the working of PN junction diode under forward and reverse biased conditions?	5 Marks	[CO1] [PO1]		
b	With the circuit diagram, explain the operation of center-tapped full wave rectifier? Draw input and output waveforms?	5 Marks	[CO1] [PO1]		
	OR				
c	Draw and explain the V-I characteristics of a silicon diode?	5 Marks	[CO1] [PO2]		
d	Explain the operation of half wave rectifier and capacitor filter with a neat circuit diagram and waveform?	5Marks	[CO1] [PO1]		
Q.4					
a	Draw CE circuit and sketch the input and output characteristics also explain the operating regions by indicating them on the characteristics curve?	6 Marks	[CO2] [PO2]		
b	Explain the basic structure and operation of JFET with neat diagrams? OR	4 Marks	[CO2] [PO2]		
c	With a neat diagram explain input, output characteristics of a transistor in a CB configuration?	5 Marks	[CO2] [PO1]		
d	Explain the operation of an enhancement MOSFET with neat circuit diagram?	5 Marks	[CO2] [PO4]		
Q.5	5				
a	Explain the block diagram of an operational amplifier?	5 Marks	[CO3] [PO1]		
b	Explain the op-amp as a adder with neat circuit diagram?	5Marks	[CO3] [PO1]		
	OR				
С	Explain the operation of an op-amp as a non-inverting amplifier with neat diagram and waveforms?	6 Marks	[CO3] [PO2]		
d	Define the following terms w.r.t op-amp?[4M]				
	(i) CMRR (ii) Slew-rate	4Marks	[CO3] [PO1]		
Q.6	0.6				
a	Realise Ex-OR using only NAND gates?	4Marks	[CO4] [PO1]		
b	State and prove De-Morgans theorems?	6Marks	[CO4] [PO2]		
OR					
c	Realize Full adder circuit using NAND gates?	3 Marks	[CO4] [PO2]		
d	Write the logical symbol, truth table and Boolean expressions of all the logic gates (AND,OR,NOT,NOR,NAND,EX-OR,EX-NOR)?	7 Marks	[CO4] [PO1]		